## Bonding in silicates: Investigation of the Si L<sub>2,3</sub> edge by parallel electron energy-loss spectroscopy

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## ABSTRACT

The Si  $L_{2,3}$  core-loss edge can be used to probe the crystal chemistry around Si, providing information on the s- and d-like partial density of unoccupied states of the Si-O bonds. We present Si  $L_{2,3}$  edges from 59 silicates, glasses, and amorphous materials acquired by parallel electron energy-loss spectroscopy (PEELS) with a transmission electron microscope (TEM) at an energy resolution of 0.7 eV. The Si  $L_{23}$ edge spectrum of  $\alpha$ -quartz is interpreted using the results of a recent pseudopotential band-structure calculation. A combination of Si s- and d-like partial density of states derived from this calculation resembles the Si  $L_{23}$  energy-loss near-edge structure (ELNES) of  $\alpha$ -quartz. The Si  $L_{23}$  ELNES of the silicates are interpreted using the results of the band-structure calculation of  $\alpha$ -quartz. The Si L<sub>2,3</sub> edges of O<sup>4</sup>, O<sup>3</sup>, O<sup>2</sup>, some Q<sup>1</sup> silicates, and amorphous materials have ELNES similar to that of  $\alpha$ -quartz, and the Q<sup>0</sup> and some  $Q^1$  silicates have ELNES different from that of  $\alpha$ -quartz. A "coordination fingerprint" is defined for  $Q^4$ ,  $O^3$ , and  $O^2$  Si L<sub>23</sub> ELNES because of their similarity to the  $\alpha$ -quartz spectrum. The similarities between the  $L_{2,3}$  core-loss edge shapes of the third-row  $XO_4^{n-}$  (X = Al, Si, S, and P) series attests to a common molecular–orbital picture of their bonding. For  $Q^0$  and some  $Q^1$  spectra a "structure fingerprint" is defined because the Si  $L_{2,3}$ -edge shapes are indicative of the number, distribution, and nature of the non-nearestneighbor atoms. Spectra of olivine glasses and metamict zircon more closely resemble the  $\alpha$ -quartz spectrum than their crystalline analogs. In contrast to previous studies, we show that distortion of the  $SiO_4$ tetrahedron is of secondary importance as an ELNES-modifying parameter. Polyhedral distortions become less important with increase in polymerization. There is a positive linear correlation between the energies of the Si  $L_{2,3}$ -edge onsets and polymerization, Si 2p and 2s binding energies, and the <sup>29</sup>Si NMR isotropic chemical shifts. The shift to higher energies of the edge onsets with polymerization corresponds to an increase in effective charge on the Si atom with higher  $Q^n$ . For silicates with isolated SiO<sub>4</sub> tetrahedra, increases in L<sub>2.3</sub>-energy onsets correlate with increases in polarizing power of the next-nearest-neighbor cations. The Si  $L_{23}$ -edge shapes are affected by the types and coordinations of the next-nearest-neighbor cations. For example, and radite, ilvaite, fayalite, and  $\gamma$ -Fe<sub>2</sub>SiO<sub>4</sub> have FeO<sub>6</sub> bonded to SiO<sub>4</sub> and exhibit similar ELNES. Topaz, dumortierite, staurolite, and kyanite have similar Si L<sub>2.3</sub> ELNES, with AlO<sub>6</sub> bonded to the SiO<sub>4</sub>. Their edge shapes are distinct from those of silicates with SiO<sub>4</sub> bonded to AlO<sub>4</sub>, as in the feldspars. A comparison of the Al and Si L<sub>23</sub> and Al, Si, O, and F K core-loss edges of topaz illustrates the influence of neighbor effects and mixing of unoccupied states. This mixing illustrates the limitations of ab initio methods that model core-loss edges that neglect non-nearest-neighbor interactions.